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**INFORMATION DISCLOSURE  
STATEMENT BY APPLICANT**

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APPLICANT: Jean-Luc Morand

GROUP ART UNIT: 2811 2814

EXAMINER: Unassigned HOAI PHAM

Sheet 1 of 1

#### U.S. PATENT DOCUMENTS

Examiner's Initials	Cite No.	U.S. Patent Document		Name of Patentee or Applicant of Cited Document	Date of Publication or of issue of Cited Document MM-DD-YYYY
		Number	Kind Code		
HP		3,069,603		Hunter	12/18/1962
		3,128,530		Rouse et al.	04/14/1964
		3,254,275		Lob	05/31/1966
		3,411,054		Cullis	11/12/1968
		3,988,764		Cline et al.	10/26/1976
		4,032,955		Anthony et al.	06/28/1977
HP		3,069,603		Hunter	12/18/1962

#### FOREIGN PATENT DOCUMENTS

Examiner's Initials	Cite No.	Foreign Patent Document			Name of Patentee or Applicant of Cited Document (not necessary)	Date of Publication of Cited Document MM-DD-YYYY	Translation (Y/N)
		Office/ Country	Number	Kind Code			
HP		WO	00/35018		Neilson et al.	06/15/2002	

#### OTHER ART — NON PATENT LITERATURE DOCUMENTS

Examiner's Initials	Cite No.	Include name of the author (in CAPITAL LETTERS) title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, relevant page(s), volume-issue number(s), publisher, city and/or country where published.	Translation (Y/N)
HP		French Search Report from corresponding French National Application No. 03/50987 filed December 5, 2003	
HP		French Search Report from related French National Application No. 03/50985 filed December 5, 2003	
HP		Zhong J.X. et al., <u>Electronic Structure of a Fractal Model of Porous Silicon</u> , J. Non-Cryst. Solids (Netherlands), December 1993, Vol. 164-166, Pt. 2, pages 969-972, XP002290027	

EXAMINER *Hoai Pham* DATE CONSIDERED 7/11/05

#EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

\*a copy of this reference is not provided as it was previously cited by or submitted to the office in a prior application, Serial No. \_\_, filed \_\_, and relied upon for an earlier filing date under 35 U.S.C. 120 (continuation, continuation-in-part, and divisional applications).

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